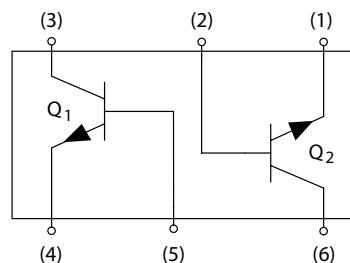
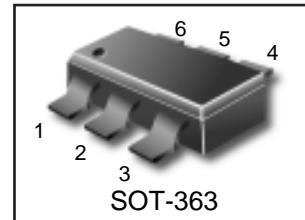


## Dual General Purpose Transistor

The LMBT3904DW1T1 device is a spin-off of our popular SOT-23/SOT-323 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-363 six-leaded surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

- hFE, 100–300
- Low V<sub>CE(sat)</sub>, ≤ 0.4 V
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Available in 8 mm, 7-inch/3,000 Unit Tape and Reel
- Device Marking: LMBT3904DW1T1 = MA

**LMBT3904DW1T1**



### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	I <sub>C</sub>	200	mAdc
Electrostatic Discharge	ESD	HBM>16000, MM>2000	V

### ORDERING INFORMATION

Device	Package	Shipping
LMBT3904DW1T1	SOT-363	3000 Units/Reel

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Package Dissipation(1) $T_A = 25^\circ\text{C}$	P <sub>D</sub>	150	mW
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	833	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

1. Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended footprint.

## LMBT3904DW1T1

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Breakdown Voltage <sup>(2)</sup> ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $I_B = 0$ )	$V_{(\text{BR})\text{CEO}}$	40	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 10 \mu\text{A}_\text{dc}$ , $I_E = 0$ )	$V_{(\text{BR})\text{CBO}}$	60	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu\text{A}_\text{dc}$ , $I_C = 0$ )	$V_{(\text{BR})\text{EBO}}$	6.0	—	Vdc
Base Cutoff Current ( $V_{CE} = 30 \text{ Vdc}$ , $V_{EB} = 3.0 \text{ Vdc}$ )	$I_{BL}$	—	50	nAdc
Collector Cutoff Current ( $V_{CE} = 30 \text{ Vdc}$ , $V_{EB} = 3.0 \text{ Vdc}$ )	$I_{CEX}$	—	50	nAdc

### ON CHARACTERISTICS (2)

DC Current Gain ( $I_C = 0.1 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ Vdc}$ ) ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ Vdc}$ ) ( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ Vdc}$ ) ( $I_C = 50 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ Vdc}$ ) ( $I_C = 100 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ Vdc}$ )	$\text{h}_{FE}$	40 70 100 60 30	— — 300 — —	—
Collector-Emitter Saturation Voltage ( $I_C = 10 \text{ mA}_\text{dc}$ , $I_B = 1.0 \text{ mA}_\text{dc}$ ) ( $I_C = 50 \text{ mA}_\text{dc}$ , $I_B = 5.0 \text{ mA}_\text{dc}$ )	$V_{CE(\text{sat})}$	— —	0.2 0.3	Vdc
Base-Emitter Saturation Voltage ( $I_C = 10 \text{ mA}_\text{dc}$ , $I_B = 1.0 \text{ mA}_\text{dc}$ ) ( $I_C = 50 \text{ mA}_\text{dc}$ , $I_B = 5.0 \text{ mA}_\text{dc}$ )	$V_{BE(\text{sat})}$	0.65 —	0.85 0.95	Vdc

### SMALL-SIGNAL CHARACTERISTICS

Current-Gain – Bandwidth Product ( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 20 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )	$f_T$	300	—	MHz
Output Capacitance ( $V_{CB} = 5.0 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{\text{obo}}$	—	4.0	pF
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{\text{ibo}}$	—	8.0	pF

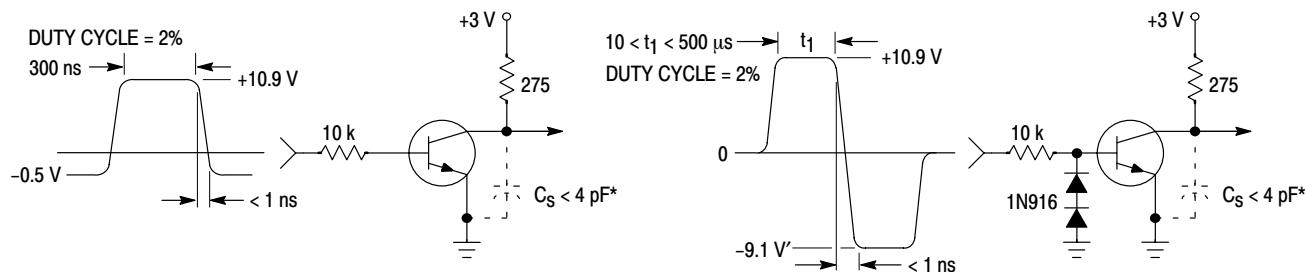
2. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

**LMBT3904DW1T1**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
Input Impedance ( $V_{CE} = 10 \text{ Vdc}$ , $I_C = 1.0 \text{ mA}$ , $f = 1.0 \text{ kHz}$ )	$h_{ie}$	1.0 2.0	10 12	$\text{k } \Omega$
Voltage Feedback Ratio ( $V_{CE} = 10 \text{ Vdc}$ , $I_C = 1.0 \text{ mA}$ , $f = 1.0 \text{ kHz}$ )	$h_{re}$	0.5 0.1	8.0 10	$\times 10^{-4}$
Small-Signal Current Gain ( $V_{CE} = 10 \text{ Vdc}$ , $I_C = 1.0 \text{ mA}$ , $f = 1.0 \text{ kHz}$ )	$h_{fe}$	100 100	400 400	—
Output Admittance ( $V_{CE} = 10 \text{ Vdc}$ , $I_C = 1.0 \text{ mA}$ , $f = 1.0 \text{ kHz}$ )	$h_{oe}$	1.0 3.0	40 60	$\mu\text{mhos}$
Noise Figure ( $V_{CE} = 5.0 \text{ Vdc}$ , $I_C = 100 \mu\text{A}$ , $R_S = 1.0 \text{ k } \Omega$ , $f = 1.0 \text{ kHz}$ )	NF	— —	5.0 4.0	dB

**SWITCHING CHARACTERISTICS**

Delay Time	( $V_{CC} = 3.0 \text{ Vdc}$ , $V_{BE} = -0.5 \text{ Vdc}$ )	$t_d$	—	35	ns
Rise Time	( $I_C = 10 \mu\text{A}$ , $I_{B1} = 1.0 \mu\text{A}$ )	$t_r$	—	35	
Storage Time	( $V_{CC} = 3.0 \text{ Vdc}$ , $I_C = 10 \mu\text{A}$ )	$t_s$	—	200	ns
Fall Time	( $I_{B1} = I_{B2} = 1.0 \mu\text{A}$ )	$t_f$	—	50	



\* Total shunt capacitance of test jig and connectors

**Figure 1. Delay and Rise Time  
Equivalent Test Circuit**
**Figure 2. Storage and Fall Time  
Equivalent Test Circuit**

## LMBT3904DW1T1

### TYPICAL TRANSIENT CHARACTERISTICS

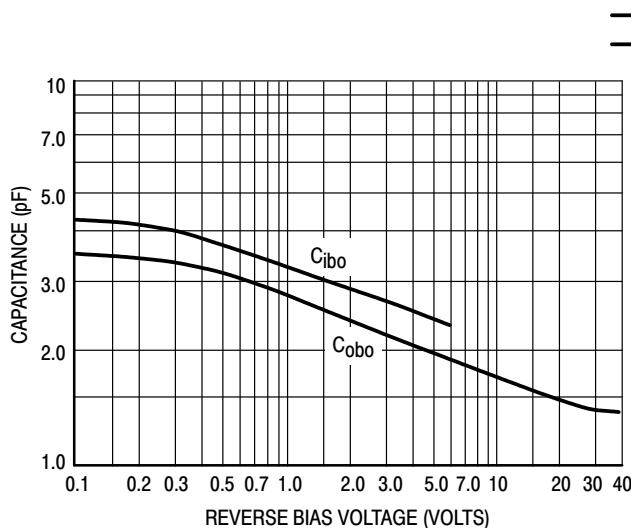


Figure 3. Capacitance

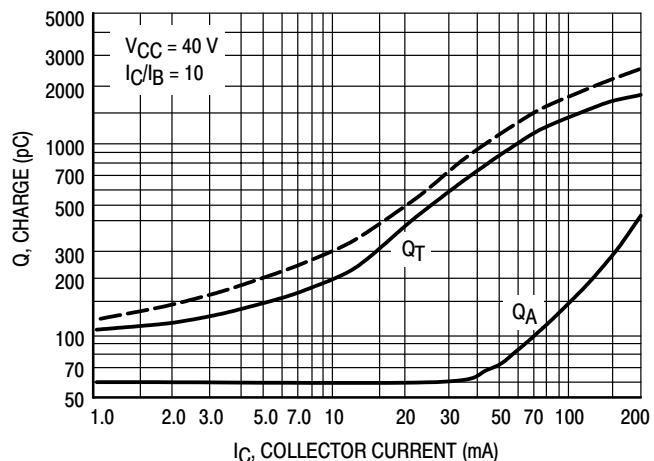


Figure 4. Charge Data

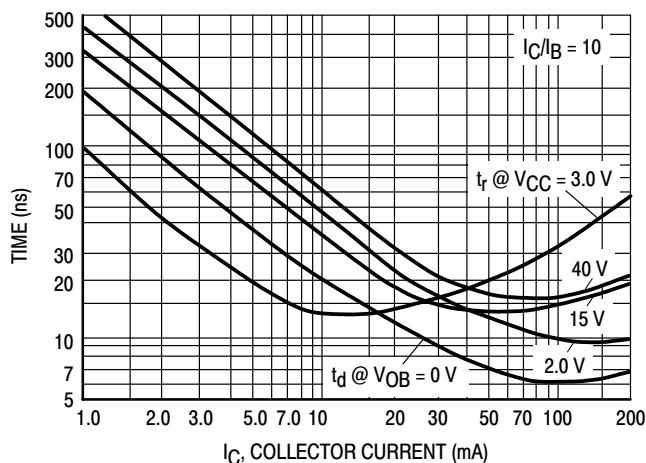


Figure 5. Turn-On Time

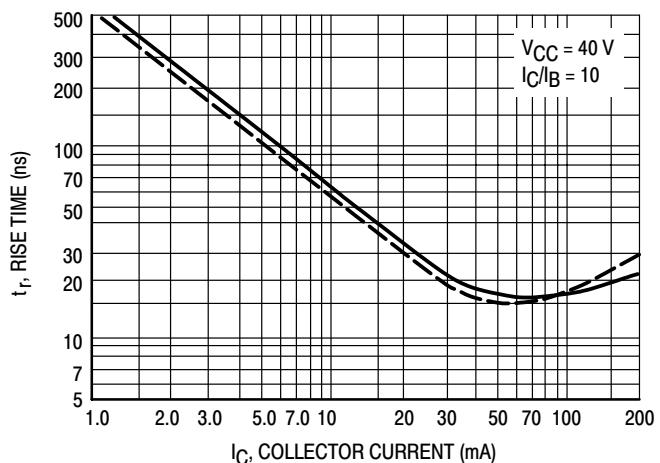


Figure 6. Rise Time

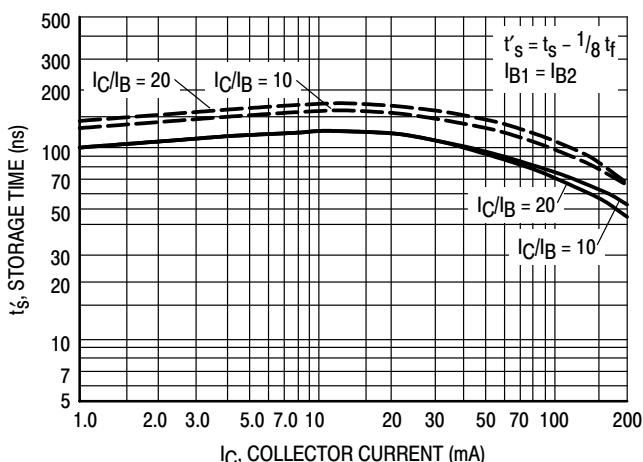


Figure 7. Storage Time

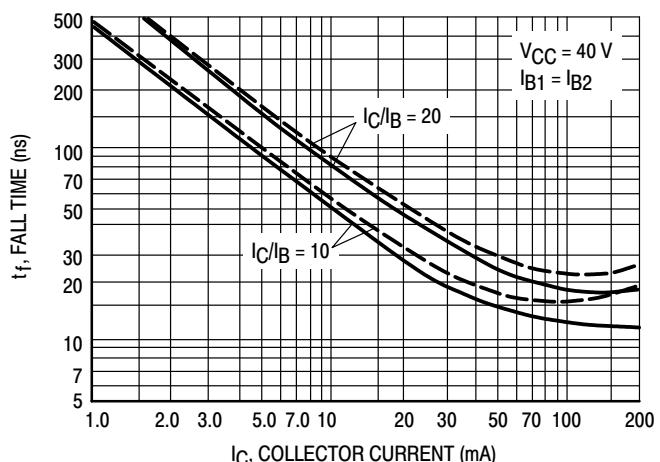


Figure 8. Fall Time

**TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS  
NOISE FIGURE VARIATIONS**

( $V_{CE} = 5.0$  Vdc,  $T_A = 25^\circ\text{C}$ , Bandwidth = 1.0 Hz)

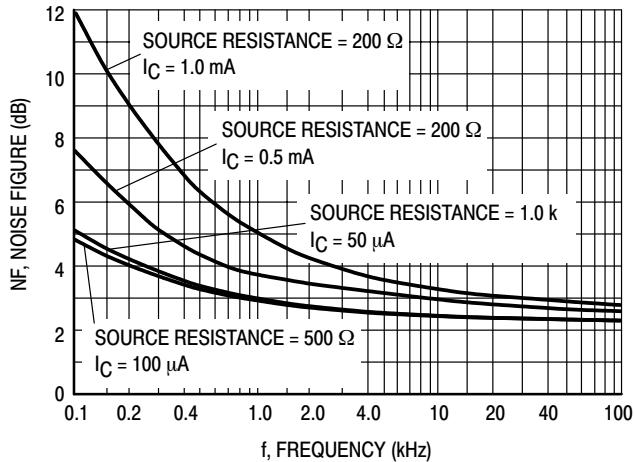


Figure 9. Noise Figure

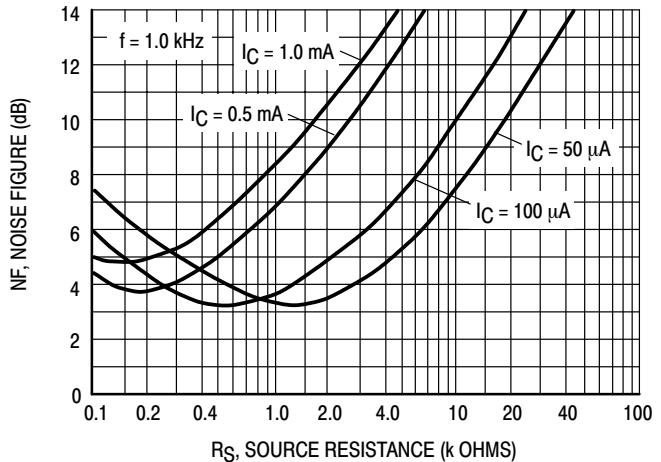


Figure 10. Noise Figure

**h PARAMETERS**

( $V_{CE} = 10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$ )

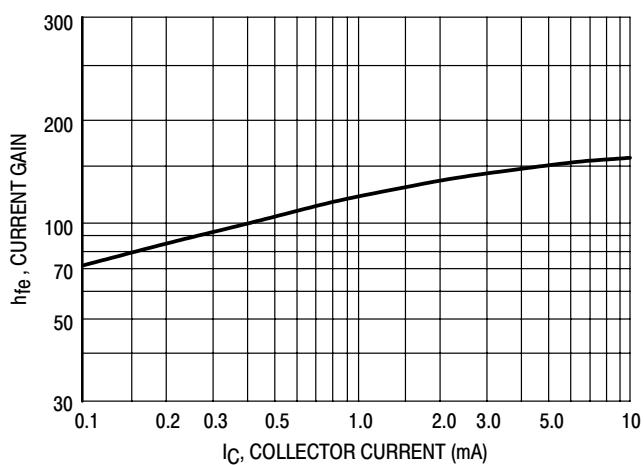


Figure 11. Current Gain

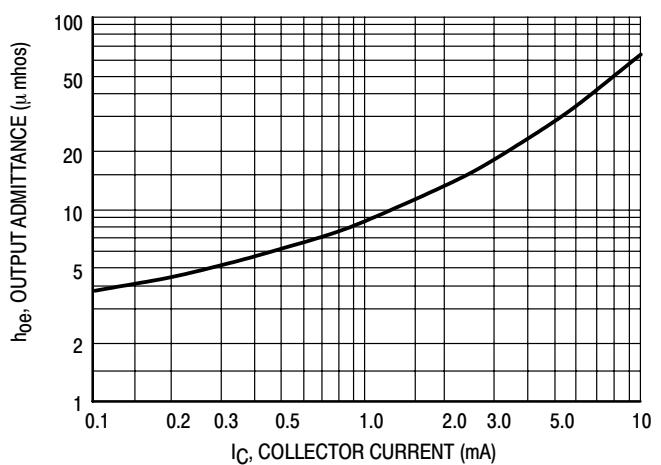


Figure 12. Output Admittance

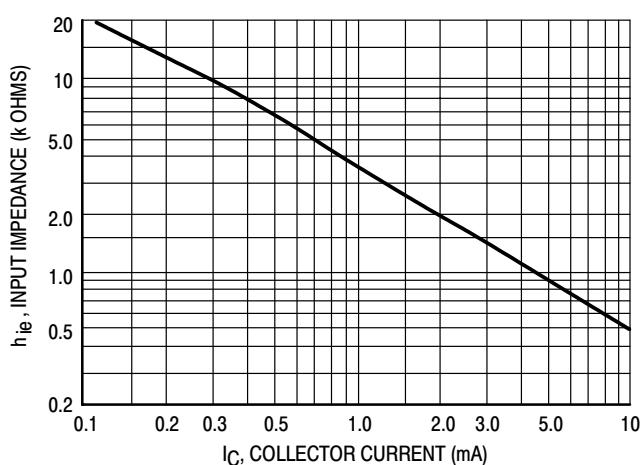


Figure 13. Input Impedance

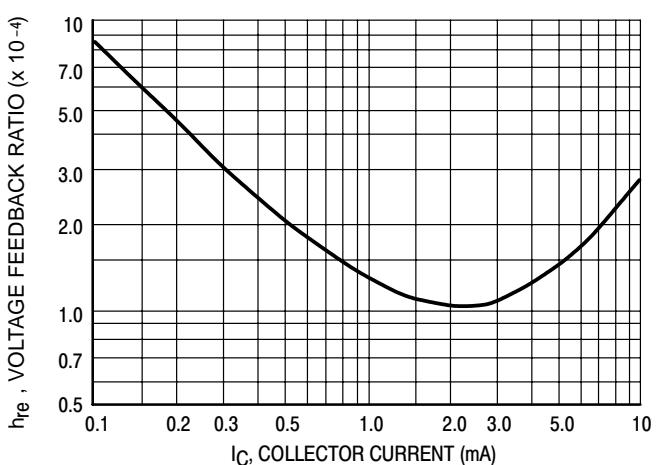


Figure 14. Voltage Feedback Ratio

## LMBT3904DW1T1

### TYPICAL STATIC CHARACTERISTICS

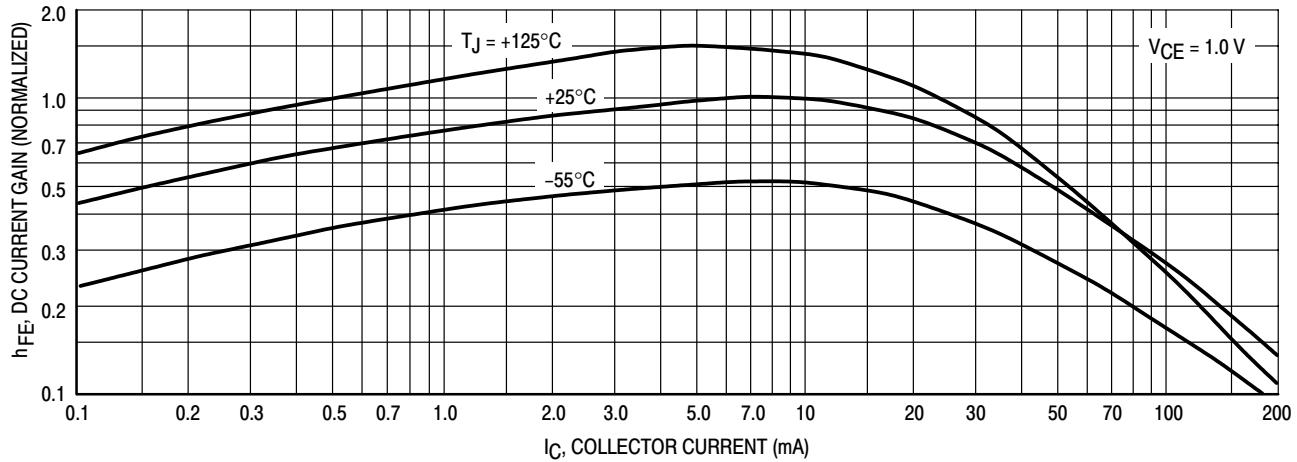


Figure 15. DC Current Gain

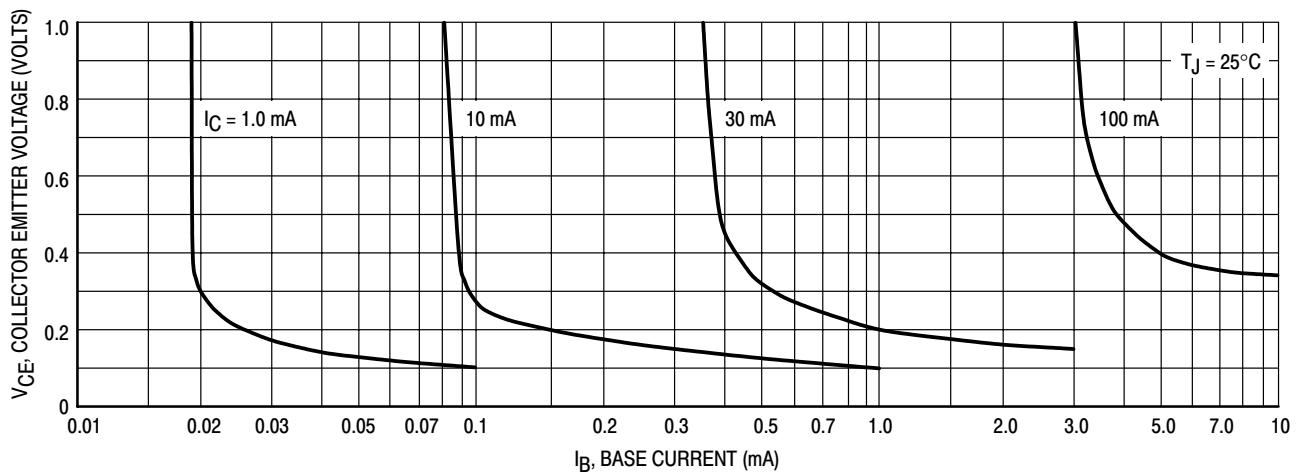


Figure 16. Collector Saturation Region

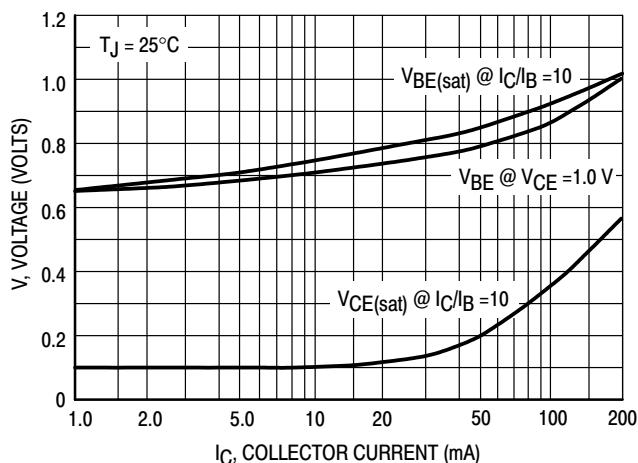


Figure 17. "ON" Voltages

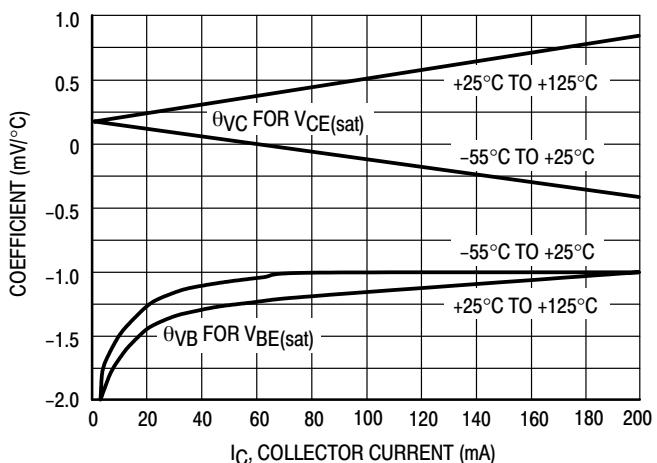


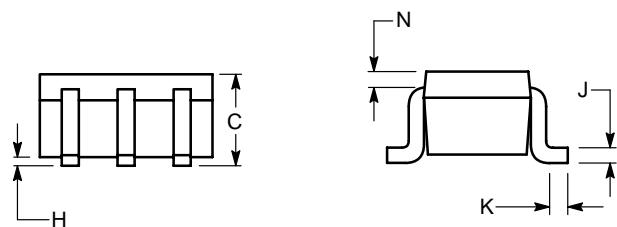
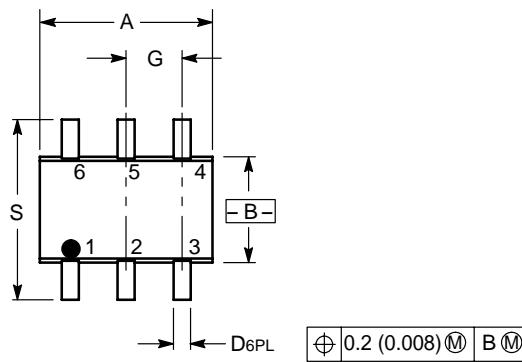
Figure 18. Temperature Coefficients

# LMBT3904DW1T1

SC-88/SOT-363

## NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

PIN 1. Emitter 2  
2. Base 2  
3. Collector 1  
4. Emitter 1  
5. Base 1  
6. Collector 2

